DATA SHEET

10GBPS 850NM VCSEL ARRAYS

V850-2092-002, V850-2093-002

FEATURES:

- 850nm cathode common VCSEL array
- Capable of 10Gbps per channel modulation
- Fully tested and Burned in with **STABILAZE**TM process
- 1x4 and 1x12 version



The V850-209x-002 are high-performance 850 nm VCSEL (Vertical Cavity Surface-Emitting Laser) array die optimized for high-speed data communications.

The array die are fully *stabilized* and tested, ideal for use in manufacturing transceivers for parallel optical interconnects. The arrays are available in either 4 or 12 channel configurations.

Each device is a high radiance VCSEL designed to convert electrical current into optical power that can be used in fiber optic communications and other applications. As the current varies above threshold, the light intensity increases proportionally.

The 850-209x-002 are designed to be used with inexpensive silicon or gallium arsenide detectors, but excellent performance can also be achieved with some indium gallium arsenide detectors.

The low drive current requirement makes direct drive from PECL (Positive Emitter Coupled Logic) or ECL (Emitter Coupled Logic) gates possible and eases driver design.

Designed to interface with 50/125 and $62.5/125\mu m$ multimode fiber, the VCSELs produce circularly symmetric, non-astigmatic, narrow divergence beams that, with appropriate lensing, fiber couple all of the emitter power.

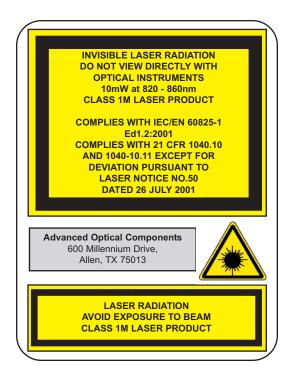
The top (anode) contact, is a minimum $1\mu m$ Au for ease of wire bonding. Wire bonding should be done with minimal pressure to ensure the VCSEL is not damaged. The backside common VCSEL cathode is also a minimum of $1\mu m$ Au metallurgy. The die must be mounted using thermally and electrical conductive media.

The VCSEL arrays are shipped on medium tack blue tape in 6 inch grip rings.



Part Number	Description	
850-2092-002	10Gbps 4 channel VCSEL die array	
850-2093-002	10Gbps 12 channel VCSEL die array	

ABSOLUTE MAXIMUM RATINGS



Parameter	Rating		
Storage temperature	-40°C to +85°C		
Case operating temperature	0 to +85 ^o C		
Lead solder temperature	260 ^o C, 10 seconds		
Reverse Power Supply Voltage	5V		
Continuous forward current	12mA		

NOTICE: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operations section for extended periods of time may affect reliability.

NOTICE: The inherent design of this component causes it to be sensitive to electrostatic discharge (ESD). To prevent ESD-induced damage and/or degradation to equipment, take normal ESD precautions when handling this product

ELECTRICAL-OPTICAL CHARACTERISTICS

 $T_A = 25^{\circ}C$ unless otherwise stated

VCSEL Parameters	Test Condition	Symbol	Min.	Тур.	Max.	Uniformity	Units	Notes
Optical Output Power	I _F = 6.5mA	PO		2.0		15%	mW	2
Threshold Current		lтн	0.5	1	1.5	0.2	mA	
Threshold Current maximum deviation from 25 ^o C value	T _A =0 to 70°C		-0.25		0.8	0.2	mA	
	T _A =25 to 85°C	Δ I _{TH}			1.5			3
	T _A =-40 to 25°C				0.75			
Temperature at minimum threshold current		т ₀	-20		20		°C	3
Slope Efficiency	T _A =25°C	η	0.3	0.4	0.6	0.05	mW/mA	
	T _A =-40°C				0.75			4
	T _A =85°C		0.19					
Slope Efficiency Temperature Variation	T _A =0 to 70°C	Δη/ΔΤ	-3000	-7000	-10000		ppm/ºC	5
Peak Wavelength	I _F =6mA T _A =0 to 70°C	λ_{P}	840	850	860	1	nm	
λ_{p} Temperature Variation	I _F =6mA T _A =-40 to 85°C	$\Delta \lambda_{P} / \Delta T$		0.06			nm/ºC	
RMS Spectral Bandwidth	I _F =6mA	Δλ			0.65		nm	
Laser Forward Voltage	I _F =6mA	V _F		1.8	2.1	0.1	V	
Roll over		P _{max}	4.0				mW	6
Rise/Fall Time	P _{avg} = 2mW, Extinction Ratio = 5dB	T _R			40 40		ps	7
Relative Intensity Noise	10GHz BW, I _F =6mA	RIN		-135	-130		dB/Hz	
Series Resistance	I _F = 6mA, T _A =25°C		40	50	60	3	Ohms	
	T _A =-40°C	R _S			75			
	T _A =85°C		30					
Series Resistance Temperature Coefficient	$I_F = 6mA$, $T_A = 0$ to 70° C	$\Delta R_{S}/\Delta T$		-3000			ppm/°C	8
Capacitance	I _F =6mA, F=1MHz	С			0.25	10%	pF	
Beam Divergence		Θ	15		30	10%	Degree	9
Beam Divergence current variation		$\Delta\Theta/\Delta$ I _F		0.6		10%	Degree/ mA	

Uniformity is the difference between the maximum and the minimum measured value across the array. **Maximum and Minimum** are defined per array.

NOTES

- 1. Reliability is a function of temperature, see www.finisar.com/aoc.php for details.
- 2. For the purpose of these tests, I_F is DC current.
- 3. Threshold current varies as $(T_A T_0)^2$. It may either increase or decrease with temperature, depending upon relationship of T_A to T_0 . The magnitude of the change is proportional to the threshold at T_0 .
- 4. Slope efficiency is defined as $\Delta P_O/\Delta I_F$.
- 5. To compute the value of Slope Efficiency at a temperature T, use the following equation:

$$\eta(T) \approx \eta(25^{\text{O}}\text{C})^*[1 + (\Delta \eta/\Delta T)^*(T\text{-}25)]$$

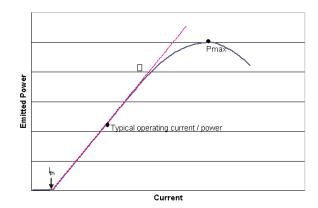
- 6. Rollover is the power at which a further current increase does not result in a power increase.
- 7. Rise and fall times specifications are the 20% 80%. Most of the devices will measure <135ps fall time. Rise and fall times are sensitive to drive electronics.
- 8. To compute the value of Series Resistance at a temperature T, use the following equation:

$$\mathsf{R}_{\mathsf{S}}(\mathsf{T}) \approx \mathsf{R}_{\mathsf{S}}(25^{\mathsf{O}}\mathsf{C})^*[1 + \Delta \mathsf{R}_{\mathsf{S}}/\!\Delta \mathsf{T})^*(\mathsf{T}\text{-}25)]$$

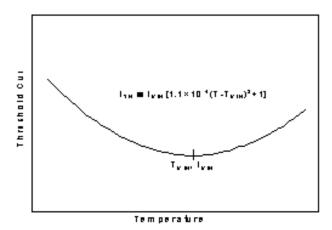
9.) Beam divergence is defined as the total included angle between the 1/e² intensity points.

TYPICAL PERFORMANCE CURVES

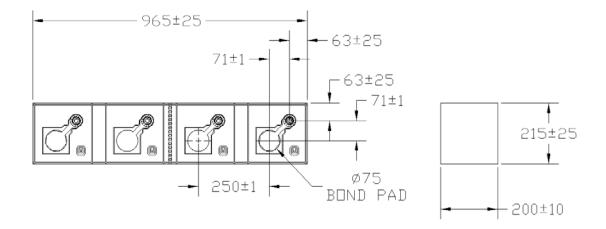
Emitted Power vs. Current: Power varies approximately linearly with current above threshold.



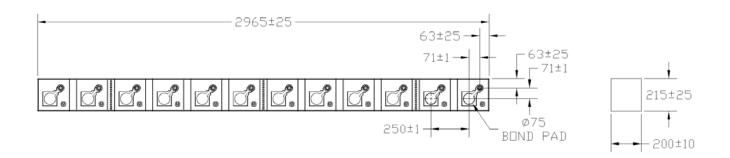
Threshold Current vs. Temperature: Threshold current varies parabolically with temperature; thus it can be nearly constant for a limited temperature range.



4-CHANNEL ARRAY



12-CHANNEL ARRAY



DIE DIMENSIONS: (μM)

Dimension	4-Channel	12-Channel
Length	965	2965
Width	215	215
Height	200	200

ADVANCED OPTICAL COMPONENTS

Finisar's ADVANCED OPTICAL COMPONENTS division was formed through strategic acquisition of key optical component suppliers. The company has led the industry in high volume Vertical Cavity Surface Emitting Laser (VCSEL) and associated detector technology since 1996. VCSELs have become the primary laser source for optical data communication, and are rapidly expanding into a wide variety of sensor applications. VCSELs' superior reliability, low drive current, high coupled power, narrow and circularly symmetric beam and versatile packaging options (including arrays) are enabling solutions not possible with other optical technologies.

ADVANCED OPTICAL COMPONENTS is also a key supplier of Fabrey-Perot (FP) and Distributed Feedback (DFB) Lasers, and Optical Isolators (OI) for use in single mode fiber data and telecommunications networks

LOCATION

- Allen, TX Business unit headquarters, VCSEL wafer growth, wafer fabrication and TO package assembly.
- Fremont, CA Wafer growth and fabrication of 1310 to 1550nm FP and DFB lasers.
- Shanghai, PRC Optical passives assembly, including optical isolators and splitters.

SALES AND SERVICE

Finisar's ADVANCED OPTICAL COMPONENTS division serves its customers through a worldwide network of sales offices and distributors. For application assistance, current specifications, pricing or name of the nearest Authorized Distributor, contact a nearby sales office or call the number listed below.

AOC CAPABILITIES

ADVANCED OPTICAL COMPONENTS' advanced capabilities include:

- 1, 2, 4, 8, and 10Gbps serial VCSEL solutions
- 1, 2, 4, 8, and 10Gbps serial SW DETECTOR solutions
- VCSEL and detector arrays
- 1, 2, 4, 8, and 10Gbps FP and DFB solutions at 1310 and 1550nm
- 1, 2, 4, 8, and 10Gbps serial LW DETECTOR solutions
- Optical Isolators from 1260 to 1600nm range
- Laser packaging in TO46, TO56, and Optical subassemblies with SC, LC, and MU interfaces for communication networks
- VCSELs operating at 670nm, 780nm, 980nm, and 1310nm in development
- Sensor packages include surface mount, various plastics, chip on board, chipscale packages, etc.
- Custom packaging options



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